2SK1070

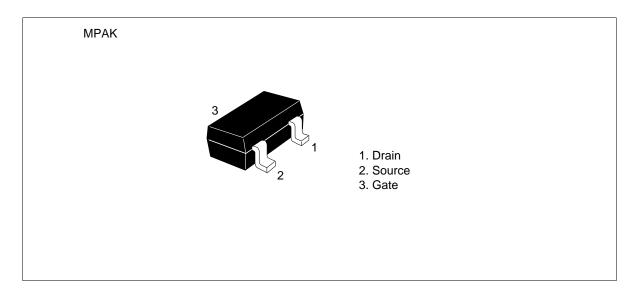
Silicon N-Channel Junction FET

HITACHI

Application

Low frequency / High frequency amplifier

Outline





2SK1070

Absolute Maximum Ratings $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Gate to drain voltage	$V_{\sf GDO}$	-22	V
Gate to source voltage	V_{GSO}	-22	V
Drain current	I _D	50	mA
Gate current	I _G	10	mA
Channel power dissipation	Pch	150	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Electrical Characteristics ($Ta = 25^{\circ}C$)

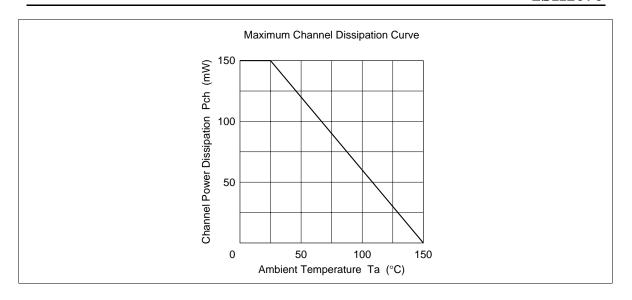
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Gate cutoff current	I _{GSS}	_	_	-10	nA	$V_{GS} = -15 \text{ V}, V_{DS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	-22	_	_	V	$I_{G} = -10 \ \mu A, \ V_{DS} = 0$
Drain current	I _{DSS} *1	6	_	40	mA	$V_{DS} = 5 \text{ V}, V_{GS} = 0, \text{ Pulse test}$
Gate to source cutoff voltage	$V_{GS(off)}$	0	_	-2.5	V	$V_{DS} = 5 \text{ V}, I_{D} = 10 \mu\text{A}$
Forward transfer admittance	y _{fs}	20	30	_	mS	$V_{DS} = 5 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$
Input capacitance	Ciss	_	9	_	pF	$V_{DS} = 5 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$

Note: 1. The 2SK1070 is grouped by I_{DSS} as follows.

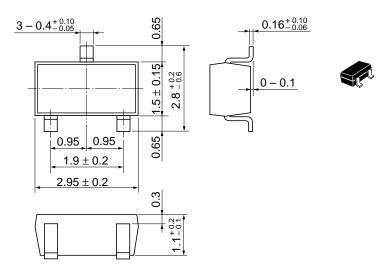
Grade	В	С	D	E
Mark	PIB	PIC	PID	PIE
I _{DSS}	6 to 14	12 to 22	18 to 30	27 to 40

See characteristic curves of 2SK435.

2SK1070



Unit: mm



Hitachi Code	MPAK
JEDEC	_
EIAJ	Conforms
Weight (reference value)	0.011 a

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